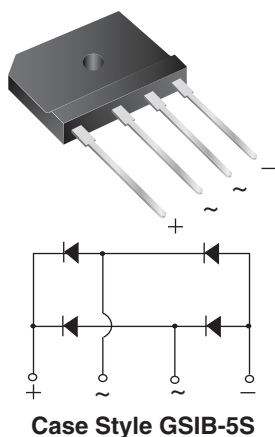




Single-Phase Single In-Line Bridge Rectifiers



FEATURES

- UL recognition file number E54214
- Thin single in-line package
- Glass passivated chip junction
- High surge current capability
- High case dielectric strength of 1500 V_{RMS}
- Solder dip 260 °C, 40 s
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

MECHANICAL DATA

Case: GSIB-5S

Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked on body

Mounting Torque: 10 cm-kg (8.8 inches-lbs) max.

Recommended Torque: 5.7 cm-kg (5 inches-lbs)

PRIMARY CHARACTERISTICS	
Package	GSIB-5S
I _{F(AV)}	6 A
V _{RRM}	200 V, 400 V, 600 V, 800 V
I _{FSM}	180 A
I _R	10 μA
V _F at I _F = 3.0 A	0.95 V
T _J max.	150 °C
Diode variations	In-Line

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VSIB620	VSIB640	VSIB660	VSIB680	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	V
Maximum RMS voltage	V _{RMS}	140	280	420	560	V
Maximum DC blocking voltage	V _{DC}	200	400	600	800	V
Maximum average forward rectified output current at	I _{F(AV)}	6.0				A
		2.8				
Peak forward surge current single sine-wave superimposed on rated load	I _{FSM}	180				A
Rating for fusing (t < 8.3 ms)	I ² t	120				A ² s
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150				°C

Notes

(1) Unit case mounted on aluminum plate heatsink

(2) Units mounted on PCB with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	VSIB620	VSIB640	VSIB660	VSIB680	UNIT
Maximum instantaneous forward voltage drop per diode	3.0 A	V _F	0.95				V
Maximum DC reverse current at rated DC blocking voltage per diode	T _A = 25 °C	I _R	10				μA
	T _A = 125 °C		250				



THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VSIB620	VSIB640	VSIB660	VSIB680	UNIT
Typical thermal resistance	$R_{\theta JA}$	22 ⁽²⁾				$^\circ\text{C/W}$
	$R_{\theta JC}$	3.4 ⁽¹⁾				

Notes

- (1) Unit case mounted on aluminum plate heatsink
- (2) Units mounted on PCB with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length
- (3) Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
VSIB660-E3/45	7.0	45	20	Tube

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

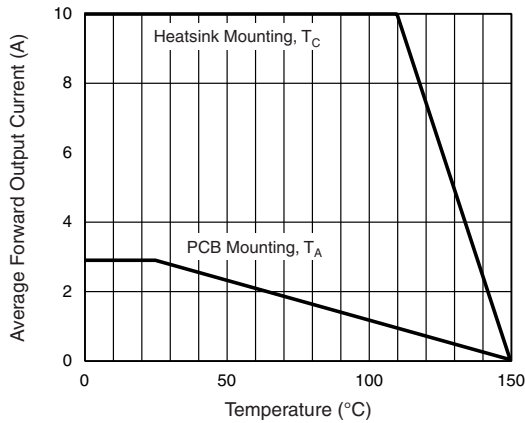


Fig. 1 - Derating Curve Output Rectified Current

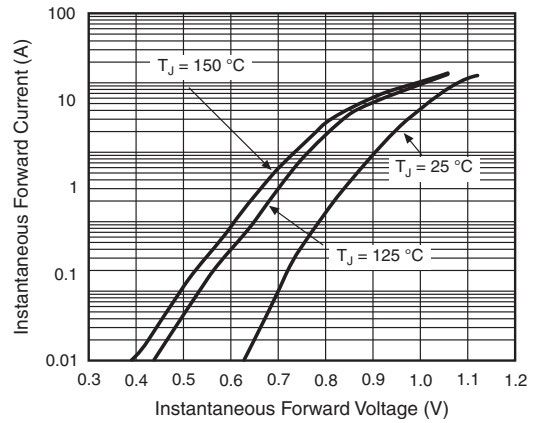


Fig. 3 - Typical Forward Characteristics Per Diode

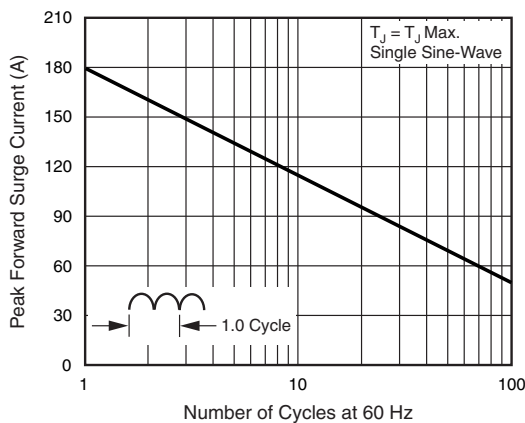


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

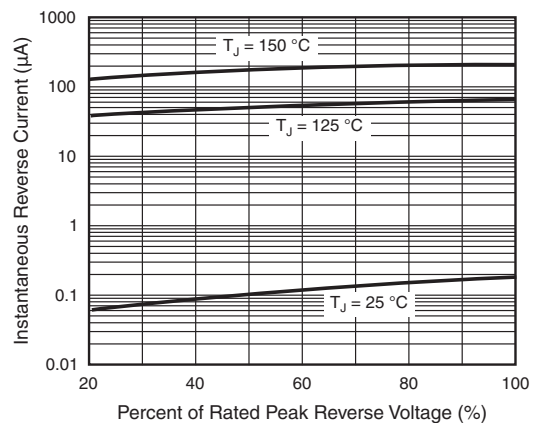


Fig. 4 - Typical Reverse Characteristics Per Diode

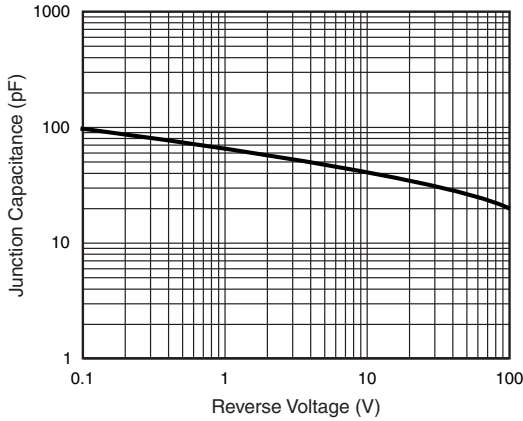


Fig. 5 - Typical Junction Capacitance Per Diode

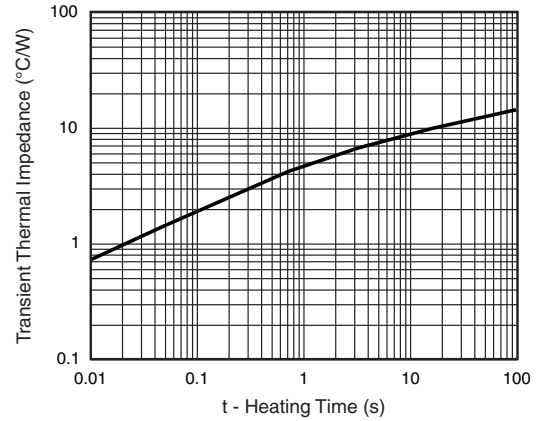


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in millimeters

Case Style GSIB-5S

